

BAV99/8

High-speed switching diode Rev. 01 — 30 March 2010

Product data sheet

1. **Product profile**

1.1 General description

High-speed switching diode in dual series configuration, encapsulated in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

- High switching speed: $t_{rr} \le 4$ ns
- Low leakage current
- Small SMD plastic package
- Low capacitance: C_d ≤ 1.5 pF
- Reverse voltage: V_R ≤ 100 V
- AEC-Q101 qualified

1.3 Applications

- High-speed switching
- General-purpose switching

Reverse polarity protection

1.4 Quick reference data

Table 1. **Quick reference data**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I _R	reverse current	$V_{R} = 80 \text{ V}$	-	-	0.5	μΑ
V_R	reverse voltage		-	-	100	V
t _{rr}	reverse recovery time		<u>[1]</u> _	-	4	ns

^[1] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.

2. **Pinning information**

Table 2. **Pinning**

Pin	Description	Simplified outline	Graphic symbol
1	anode (diode 1)		
2	cathode (diode 2)	3	3
3	cathode (diode 1), anode (diode 2)	1 2	1 2 006aaa763



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3. Ordering information

Table 3. Ordering information

Type number	Package			
	Name	Description	Version	
BAV99/8	-	plastic surface-mounted package; 3 leads	SOT23	

4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
BAV99/8	MF*

[1] * = -: made in Hong Kong

* = p: made in Hong Kong

* = t: made in Malaysia

* = W: made in China

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V_{RRM}	repetitive peak reverse voltage		-	100	V
V_R	reverse voltage		-	100	V
I _F	forward current		<u>[1]</u> _	215	mA
			[2] _	125	mA
I _{FRM}	repetitive peak forward current		-	500	mA
I _{FSM}	non-repetitive peak forward current	square wave	[3]		
		$t_p = 1 \mu s$	-	4	Α
		$t_p = 1 \text{ ms}$	-	1	Α
		t _p = 1 s	-	0.5	А
P _{tot}	total power dissipation	$T_{amb} \leq 25~^{\circ}C$	<u>[1][4]</u> _	250	mW
Per device					
T _j	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Single diode loaded.

^[2] Double diode loaded.

^[3] $T_j = 25$ °C prior to surge.

^[4] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2]	-	500	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		-	-	360	K/W

^[1] Single diode loaded.

7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

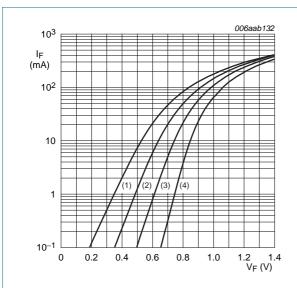
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode)					
V_{F}	forward voltage	$I_F = 1 \text{ mA}$	-	-	715	mV
		I _F = 10 mA	-	-	855	mV
		I _F = 50 mA	-	-	1	V
		I _F = 150 mA	-	-	1.25	V
I _R reverse current	V _R = 25 V	-	-	30	nA	
	V _R = 80 V	-	-	0.5	μΑ	
		V _R = 25 V; T _j = 150 °C	-	-	30	μΑ
		$V_R = 80 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	50	μΑ
C _d	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	-	1.5	pF
t _{rr}	reverse recovery time		<u>[1]</u> _	-	4	ns
V_{FR}	forward recovery voltage		[2] _	-	1.75	V

^[1] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

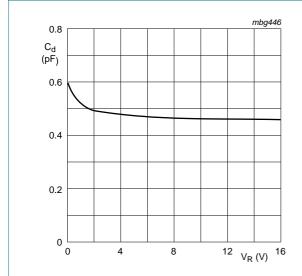
^[2] When switched from I_F = 10 mA; t_r = 20 ns.

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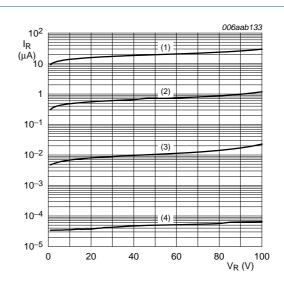
- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$
- (4) $T_{amb} = -40 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



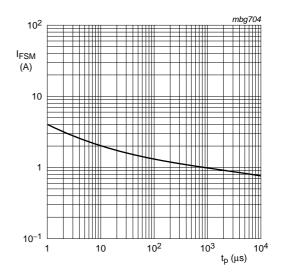
 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ }^{\circ}\text{C}$

Fig 3. Diode capacitance as a function of reverse voltage; typical values



- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$
- (4) $T_{amb} = -40 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values

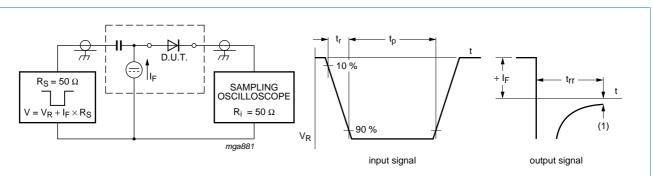


Based on square wave currents.

 $T_i = 25 \,^{\circ}\text{C}$; prior to surge

Fig 4. Non-repetitive peak forward current as a function of pulse duration; maximum values

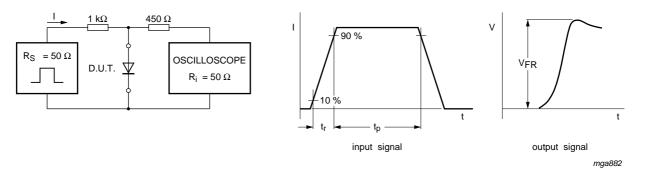
8. Test information



(1) $I_R = 1 \text{ mA}$

Input signal: reverse pulse rise time t_r = 0.6 ns; reverse voltage pulse duration t_p = 100 ns; duty cycle δ = 0.05 Oscilloscope: rise time t_r = 0.35 ns

Fig 5. Reverse recovery time test circuit and waveforms



Input signal: forward pulse rise time t_r = 20 ns; forward current pulse duration $t_p \ge 100$ ns; duty cycle $\delta \le 0.005$

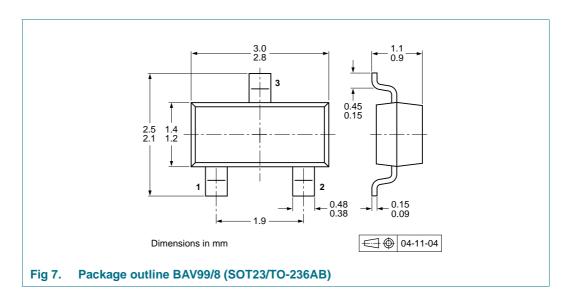
Fig 6. Forward recovery voltage test circuit and waveforms

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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9. Package outline



10. Packing information

Table 8. Packing methods

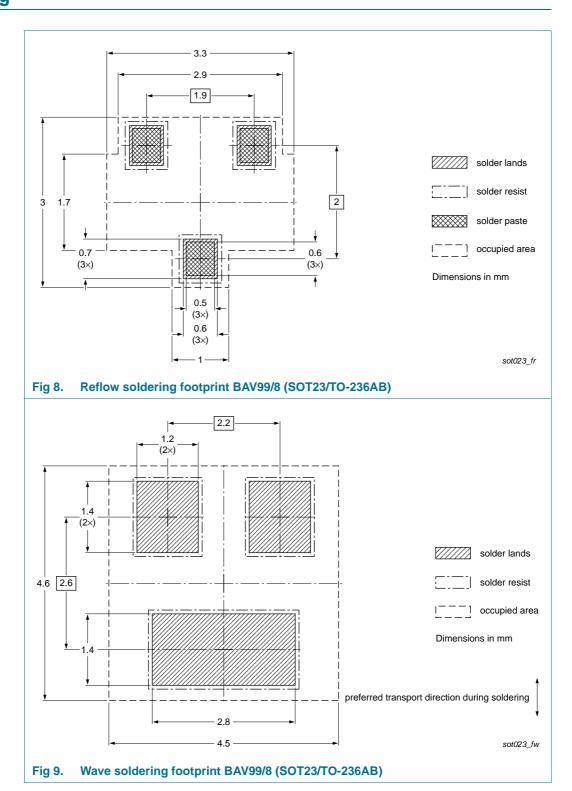
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing of	Packing quantity	
			3000	10000	
BAV99/8	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235	

^[1] For further information and the availability of packing methods, see Section 14.

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11. Soldering



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12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAV99_8_1	20100330	Product data sheet	-	-

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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